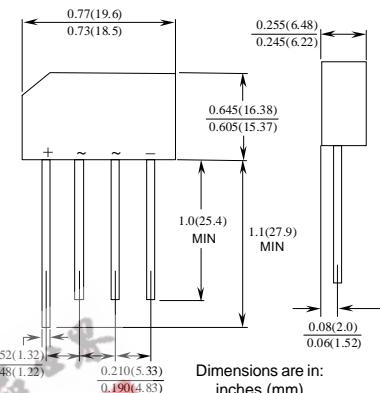


## KBL005 - KBL10

### Features

- Ideal for printed circuit board.
- Reliable low cost construction.
- High surge current capability.



Dimensions are in:  
inches (mm)

### 4.0 Ampere Silicon Bridge Rectifiers

#### Absolute Maximum Ratings\*

T<sub>A</sub> = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
I <sub>O</sub>	Average Rectified Current @ T <sub>A</sub> = 40°C	4.0	A
i <sub>f(surge)</sub>	Peak Forward Surge Current 8.3 ms single half-sine-wave Superimposed on rated load (JEDEC method)	200	A
P <sub>D</sub>	Total Device Dissipation Derate above 25°C	6.58 53	W mW/°C
R <sub>θJA</sub>	Thermal Resistance, Junction to Ambient,** per leg	19	°C/W
R <sub>θJL</sub>	Thermal Resistance, Junction to Lead,** per leg	2.4	°C/W
T <sub>stg</sub>	Storage Temperature Range	-55 to +150	°C
T <sub>J</sub>	Operating Junction Temperature	-55 to +150	°C

\*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

\*\*Device mounted on PCB with 0.375" (9.5 mm) lead length and 0.5 x 0.5" (13 x 13 mm) copper pads.

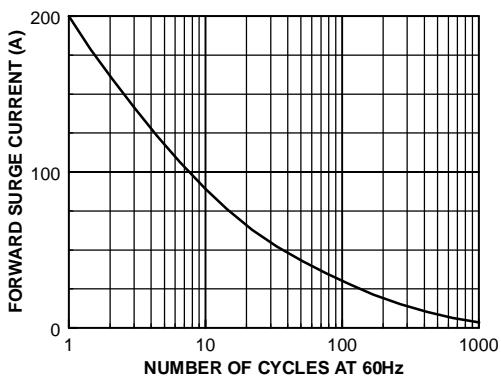
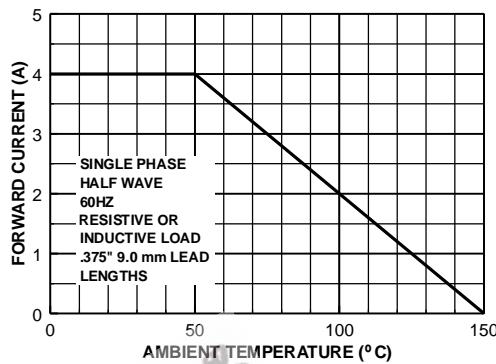
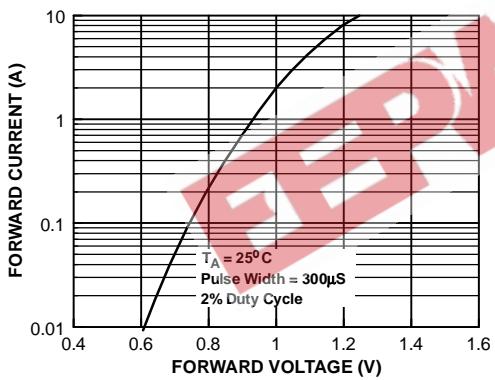
#### Electrical Characteristics

T<sub>A</sub> = 25°C unless otherwise noted

Parameter	Device							Units
	005	01	02	04	06	08	10	
Peak Repetitive Reverse Voltage	50	100	200	400	600	800	1000	V
Maximum RMS Bridge Input Voltage	35	70	140	280	420	560	700	V
DC Reverse Voltage (Rated V <sub>R</sub> )	50	100	200	400	600	800	1000	V
Maximum Reverse Leakage, total bridge @ rated V <sub>R</sub> T <sub>A</sub> = 25°C T <sub>A</sub> = 100°C				5.0	500			µA µA
Maximum Forward Voltage Drop, per bridge @ 4.0 A				1.1				V

## Silicon Bridge Rectifiers (continued)

### Typical Characteristics

**Non-Repetitive Surge Current****Forward Current Derating Curve****Forward Characteristics****Reverse Characteristics**